

SFA50UP20DN

50A, 200V Ultrafast Dual Diode

Features

- Ultrafast Soft Recovery: $T_{rr}=32\text{ns}$
- Typical Forward Voltage: $V_F=0.966\text{V}$
- Reverse Voltage: $V_{RRM}=200\text{V}$
- Avalanche Energy Rated

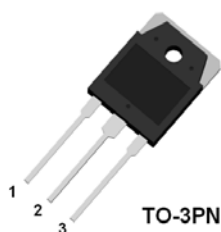
Description

The SFA50UP20DN is an ultrafast dual diode with low forward voltage drop. This device is designed for FWD in motor and power switching applications. It is specially suited for use in switching power supplies and industrial applications as welder.

Applications

- General Rectifier
- Output Rectifier in Switching Power Supply & Welder
- FWD for Motor Application

Package Type & internal Circuit



TO-3PN



1. Anode 2.Cathode 3.Anode

Absolute Maximum Ratings

per diode at $T_c=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter		Ratings	Unit
V_{RRM}	Peak Repetitive Reverse Voltage		200	V
V_{RWM}	Working Peak Reverse Voltage		200	V
V_R	DC Blocking Voltage		200	V
$I_{F(AV)}$	Average Rectified Forward Current	per device at $T_c=120^\circ\text{C}$	50	A
I_{FSM}	Non-repetitive Peak Surge Current		250	A
T_J	Operating Junction Temperature Range		$-65\sim+150$	$^\circ\text{C}$
T_{STG}	Storage Temperature Range		$-65\sim+150$	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	Ratings	Unit
$R_{th(J-C)}$	Thermal Resistance, Junction to case	1.4	$^\circ\text{C/W}$

Electrical Characteristics per diode @T_C=25 °C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V _F	Forward Voltage Drop	I _F =25A	-	0.966	1.2	V
		I _F =25A, T _C =125 °C	-	0.9	-	V
I _R	Reverse Leakage Current	V _R =200V	-	-	10	uA
T _{rr}	Reverse Recovery Time	I _F =25A, di/dt=-200A/us	-	32	40	ns
E _{AS}	Avalanche Energy	L=30mH	20	-	-	mJ

Package Dimensions

TO-3PN

(Dimensions in Millimeters)

